L Number	Hits	Search Text	DB	Time stamp
1	2	("5804506").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/05 11:50
2	2	("5972769").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/05 10:56
3	2	("6376303").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/05 10:57
4	2	("5827783").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/05 13:11
5	5502	((257/68) or (257/71) or (257/277) or (257/296) or (257/298) or (257/300) or (257/303) or (257/306) or (257/516) or (257/532) or (257/906)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/05 13:12
6	13	(((257/68) or (257/71) or (257/277) or (257/296) or (257/298) or (257/300) or (257/303) or (257/306) or (257/516) or (257/532) or (257/906)).CCLS.) and corrugat$3 near15 (capacitor or capacitance) and memory.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/05 13:13
-	0	("(boro-silicate adj glass or bpsg or germanium adj boro-silicate glass or ge-bpsg) and capacitor and dram and (corrugat$3 or rippl$3)").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 13:58
-	77	(boro-silicate adj glass or bpsg or germanium adj boro-silicate glass or ge-bpsg) and capacitor and dram and (corrugat$3 or rippl$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:10
-	0	((boro-silicate adj glass or bpsg or germanium adj boro-silicate glass or ge-bpsg) and capacitor and dram and (corrugat$3 or rippl$3)) and (rippl$3 or corrugat$3) near12 (capacitor adj2 wall)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:00
-	3	((boro-silicate adj glass or bpsg or germanium adj boro-silicate glass or ge-bpsg) and capacitor and dram and (corrugat$3 or rippl$3)) and (rippl$3 or corrugat$3) near12 (capacitor adj2 (plate or wall))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:00
-	43	(((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack$2 or alternat$3)) same capacitor and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:14
-	43	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack$2 or alternat$3)) same capacitor) and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:14

–	0	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack$2 or alternat$3)) same (rippl$3 or corrugat$3) same capacitor) and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:15
–	41	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack$2 or alternat$3)) same capacitor) and (rippl$3 or stack$2) and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:16
–	2	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack$2 or alternat$3)) same capacitor) and ((rippl$3 or stack$2) near12 (capacitor adj2 (plate or wall))) and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:19
–	0	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack$2 or alternat$3)) same capacitor) and ((rippl$3 or corrugat$2) near12 (capacitor adj2 (plate or wall))) and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:20
–	0	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack$2 or alternat$3)) same capacitor) and ((rippl$3 or corrugat$2) near12 (plate or wall)) and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:20
–	0	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack$2 or alternat$3)) same capacitor) and ((rippl$3 or corrugat$2) near12 (plate or wall)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:21
–	0	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack$2 or alternat$3)) same capacitor) and ((rippl$3 or corrugat$2) near12 (plate or wall))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:21
–	0	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack$2 or alternat$3)) same capacitor) and ((rippl$3 or corrugat$2))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:22
–	2	(((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 capacitor) and ((rippl$3 or corrugat$2) near12 capacitor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15:32
–	0	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (borosilicate or boro-silicate) adj glass) near12 (capacitance or capacitor or stacked or stacking)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15:35

—	512	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (borosilicate or boro-silicate) adj glass or bpsg) near12 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15:37
—	51	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near12 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15:37
—	646	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) with (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15:37
—	51	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15:37
—	38	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15:38
—	30	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram	USPAT	2002/02/08 15:46
—	0	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram and corrugat$3	USPAT	2002/02/08 15:40
—	0	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram and corrugat$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15:40
—	0	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram and (rippl$3 or corrugat$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15:41
—	0	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram and (rippl$3 or corrugat$3 or standing adj wav$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15:42
—	30	(ge-bpsg and (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram	USPAT	2002/02/08 15:47

–	0	(ge-bpsg and (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and (rippl$3 or corrugat$3) and dram	USPAT	2002/02/08 15:48
–	0	(ge-bpsg and (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and (rippl$3 or corrugat$3)	USPAT	2002/02/08 15:49
–	0	(ge-bpsg near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly)) and (rippl$3 or corrugat$3)	USPAT	2002/02/08 15:50
–	0	(ge-bpsg or germanium-boro-phospho adj silicate adj glass or germanium adj boro-phospho adj silicate adj glass or germanium-boro-phospho-silicate adj glass or germanium adj boro adj phospho adj silicate adj glass) same (stacked or stacking or alternating or alternate or alternately or multi-layer or multi adj layer or laminat$3)	USPAT	2002/02/08 15:56
–	2	ge-bpsg or germanium-boro-phospho adj silicate adj glass or germanium adj boro-phospho adj silicate adj glass or germanium-boro-phospho-silicate adj glass or germanium adj boro adj phospho adj silicate adj glass or ge-bpsg	USPAT	2002/02/08 15:56
–	1	5648175.pn.	USPAT	2002/02/09 10:09
–	14	(("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.	USPAT	2002/02/09 10:14
–	0	((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) and corrugat$3 and capacit$3 and bpsg and ge-bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:14
–	0	((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) and capacit$3 and bpsg and ge-bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:14
–	118	((increase near5 capacitance) near5 surface) near5 (rough$5 or etch$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:18
–	0	((increase near5 capacitance) near5 surface) near5 (rough$5 or etch$3) and "L14"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:17
–	0	((increase near5 capacitance) near5 surface) near5 (rough$5 or etch$3) and "L14"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:17

-	131	((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) or (((increase near5 capacitance) near5 surface) near5 (rough$5 or etch$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:18
-	35	(((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) or (((increase near5 capacitance) near5 surface) near5 (rough$5 or etch$3))) and ((increas$3 near5 capacitance) near5 etch$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:21
-	6	((((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) or (((increase near5 capacitance) near5 surface) near5 (rough$5 or etch$3))) and ((increas$3 near5 capacitance) near5 etch$3)) and bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:41
-	2	(((((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) or (((increase near5 capacitance) near5 surface) near5 (rough$5 or etch$3))) and ((increas$3 near5 capacitance) near5 etch$3)) and bpsg) and germanium	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:42
-	166	different adj etch$3 adj2 rates and bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:42
-	0	(different adj etch$3 adj2 rates near5 bpsg) near5 capacitance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:43
-	11	different adj etch$3 adj2 rates near5 bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 11:09
-	507	etch$3 adj rate same bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 11:09
-	318	etch$3 adj rate with bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 11:09
-	1	etch$3 adj rate with (bpsg and (ge-bpsg or germanium))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 16:42

–	3	5827783.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 17:35
–	68	(bst same capacitor same dielectric) and memory adj device.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 17:36
–	25	(bst near6 capacitor near6 dielectric) and memory adj device.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 17:55
–	2	((si-ge or silicon-germanium) same capacitor same dielectric) and memory adj device.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 22:09
–	2	5930106.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 18:01
–	4791	((257/68) or (257/71) or (257/277) or (257/296) or (257/298) or (257/300) or (257/303) or (257/306) or (257/516) or (257/532) or (257/906)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 22:10
–	3	((("257/68") or ("257/71") or ("257/277") or ("257/296") or ("257/298") or ("257/300") or ("257/303") or ("257/306") or ("257/516") or ("257/532") or ("257/906")).CCLS.) and bpsg and germanium and capacitor and memory adj2 device.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 22:11
–	3	5827783.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 22:12
–	3	5804506.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 22:13
–	3	5889696.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 22:13
–	2	5889696.pn.	USPAT; DERWENT	2002/02/10 09:09
–	2	5930106.pn.	USPAT; DERWENT	2002/02/10 09:10
–	0	(323/539).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/08 16:56
–	1364	(band adj gap or bandgap) adj reference near5 voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/08 16:57
–	275	(bandgap) adj reference near5 voltage and bipolar adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/08 16:58

— 155 (327/539).CCLS.   USPAT;   2002/05/08 16:58
                        US-PGPUB;
                        EPO; JPO;
                        DERWENT;
                        IBM_TDB